

LITE-ON TECHNOLOGY CORPORATION

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FEATURES

0.56 INCH (14.22 mm) DIGIT HEIGHT.
CONTINUOUS UNIFORM SEGMENTS.
LOW POWER REQUIREMENT.
EXCELLENT CHARACTERS APPEARANCE.
HIGH BRIGHTNESS & HIGH CONTRAST.
WIDE VIEWING ANGLE.
SOLID STATE RELIABILITY.
CATEGORIZED FOR LUMINOUS INTENSITY.

DESCRIPTION

The LTS-5501AB is a 0.56 inch (14.22 mm) digit height single digit display. This device utilizes blue LED chips which are made from GaN on a SiC substrate, and has a gray face and white segments.

DEVICE

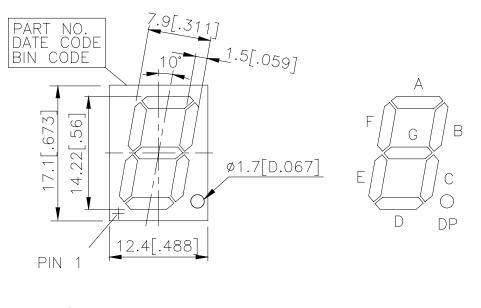
PART NO.	DESCRIPTION			
BLUE	COMMON ANODE			
LTS-5501AB	RT. HAND DECIMAL			

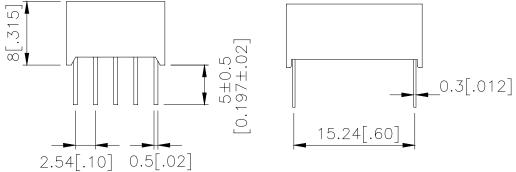
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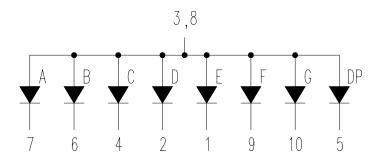
PACKAGE DIMENSIONS





NOTES: All dimensions are in millimeters. Tolerances are \pm 0.25-mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



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PIN CONNECTION

No.	CONNECTION
1	CATHODE E
2	CATHODE D
3	COMMON ANODE
4	CATHODE C
5	CATHODE D.P.
6	CATHODE B
7	CATHODE A
8	COMMON ANODE
9	CATHODE F
10	CATHODE G

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ABSOLUTE MAXIMUM RATING AT Ta=25°C

PARAMETER	MAXIMUM RATING	UNIT			
Power Dissipation Per Segment	115	mW			
Peak Forward Current Per Segment (1/10 Duty Cycle, 0.1ms Pulse Width)	60	mA			
Continuous Forward Current Per Segment	25	mA			
Derating Linear From 25 ^o C Per Segment	0.33	mA/ ⁰ C			
Reverse Voltage Per Segment	5	V			
Operating Temperature Range	-35°C to +85°C				
Storage Temperature Range	-35°C to +85°C				
Solder Temperature 1/16 inch Below Seating Plane for 3 Seconds at 260°C					

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

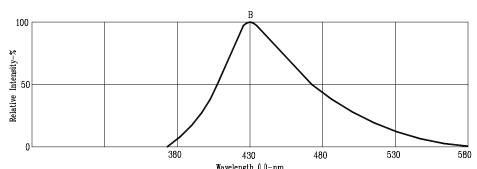
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	Iv	1300	4300		μcd	I _F =10mA
Peak Emission Wavelength	λр		428		nm	I _F =20mA
Spectral Line Half-Width	Δλ		65		nm	I _F =20mA
Dominant Wavelength	λd		466		nm	I _F =20mA
Forward Voltage Per Segment	$V_{\rm F}$		3.8	4.5	V	I _F =20mA
Reverse Current Per Segment	Ir			100	μΑ	V _R =5V
Luminous Intensity Matching Ratio	Iv-m			2:1		I _F =10mA

Note:Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

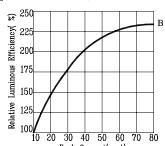
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TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

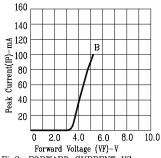
(25°C Ambient Temperature Unless Otherwise Noted)



Wavelength (I)-nm.
Fig1. RELATIVE INTENSITY VS. WAVELENGTH



Peak Current(mA)
Fig2. RELATIVE LUMINOUS EFFICIENCY
VS. PEAK FORWARD CURRENT
(250us pulse width; 2ms period)



Forward Voltage (VF)-V Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

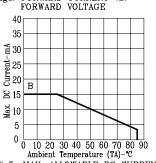


Fig5. MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE.

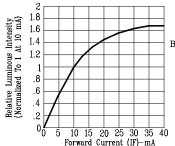
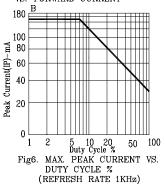


Fig4. RELATIVE LUMINOUS INTENSITY
VS. FORWARD CURRENT



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